

Features

- Split Gate Trench MOSFET Technology
- Excellent Package For Heat Dissipation
- Moisture Sensitivity Level 1
- Halogen Free. "Green" Device (Note 1)
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

Maximum Ratings

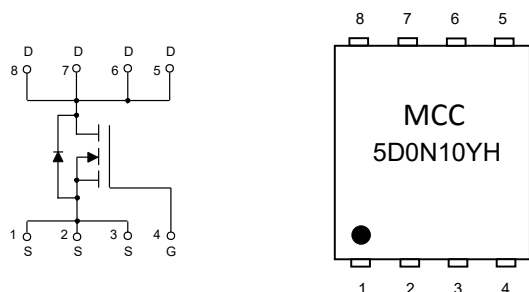
- Operating Junction Temperature Range : -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance: 44°C/W Junction to Ambient (Note2)
- Thermal Resistance: 0.6°C/W Junction to Case

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V_{DS}	100	V
Gate-Source Voltage	V_{GS}	±20	V
Continuous Drain Current	I_D	150	A
		94	
Pulsed Drain Current (Note3)	I_{DM}	600	A
Total Power Dissipation (Note4)	P_D	208	W
Single Pulse Avalanche Energy (Note 5)	E_{AS}	118	mJ

Note:

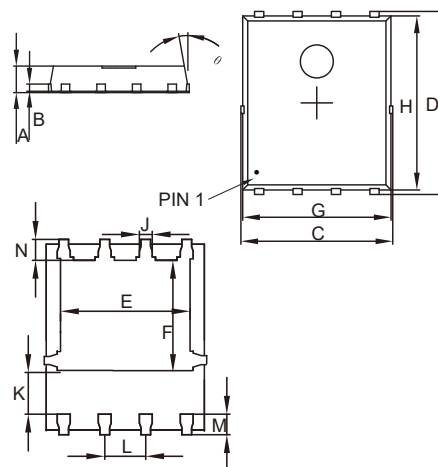
1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
2. The value of $R_{\theta JA}$ is measured with the device mounted on 1in² FR-4 board with 2oz. Copper, in a still air environment with $T_A = 25^\circ\text{C}$.
3. Repetitive rating; pulse width limited by max. junction temperature.
4. P_D is based on max. junction temperature, using junction-case thermal resistance.
5. $T_J = 25^\circ\text{C}$, $V_{DD} = 50\text{V}$, $V_{GS} = 10\text{V}$, $R_G = 25\Omega$.

Internal Structure and Marking Code



N-CHANNEL MOSFET

DFN5060



DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	0.039	0.047	0.80	1.20	
B	0.010		0.254		TYP.
C	0.203	0.219	5.15	5.55	
D	0.234	0.250	5.95	6.35	
E	0.154	0.170	3.92	4.32	
F	0.139	0.154	3.52	3.92	
G	0.197	0.213	5.00	5.40	
H	0.223	0.239	5.66	6.06	
K	0.0444	0.052	1.12	1.32	
J	0.016	0.020	0.41	0.51	
L	0.046	0.054	1.17	1.37	
M	0.022	0.030	0.56	0.76	
N	0.016	0.024	0.40	0.60	

Electrical Characteristics @ 25°C (Unless Otherwise Specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} =0V, I _D =250μA	100			V
Gate-Source Leakage Current	I _{GSS}	V _{DS} =0V, V _{GS} =±20V			±100	nA
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =100V, V _{GS} =0V			1	μA
Gate-Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =250μA	2	3	4	V
Drain-Source On-Resistance	R _{DS(on)}	V _{GS} =10V, I _D =20A		3.8	5	mΩ
Gate Resistance	R _G	f=1MHz, Open drain		1.5		Ω
Diode Characteristics						
Continuous Body Diode Current	I _S				150	A
Diode Forward Voltage	V _{SD}	V _{GS} =0V, I _S =35A			1.2	V
Reverse Recovery Time	t _{rr}	I _F =45A, di/dt=100A/μs		50		ns
Reverse Recovery Charge	Q _{rr}			73		nC
Dynamic Characteristics						
Input Capacitance	C _{iss}	V _{DS} =50V, V _{GS} =0V, f=1MHz		5180		pF
Output Capacitance	C _{oss}			719		
Reverse Transfer Capacitance	C _{rss}			21		
Total Gate Charge	Q _g	V _{DS} =50V, V _{GS} =10V, I _D =45A		98		nC
Gate-Source Charge	Q _{gs}			23		
Gate-Drain Charge	Q _{gd}			37		
Turn-On Delay Time	t _{d(on)}	V _{DD} =50V, V _{GS} =10V, R _G =5.6Ω, I _D =45A		31		ns
Turn-On Rise Time	t _r			130		
Turn-Off Delay Time	t _{d(off)}			71		
Turn-Off Fall Time	t _f			46		

Curve Characteristics

Fig.1 - Typical Output Characteristics

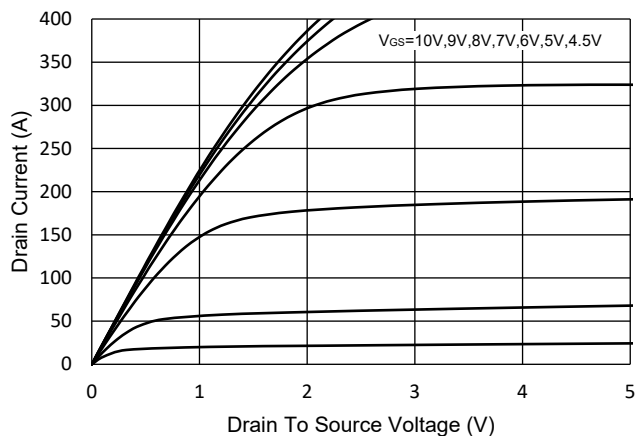


Fig.2 - Transfer Characteristic

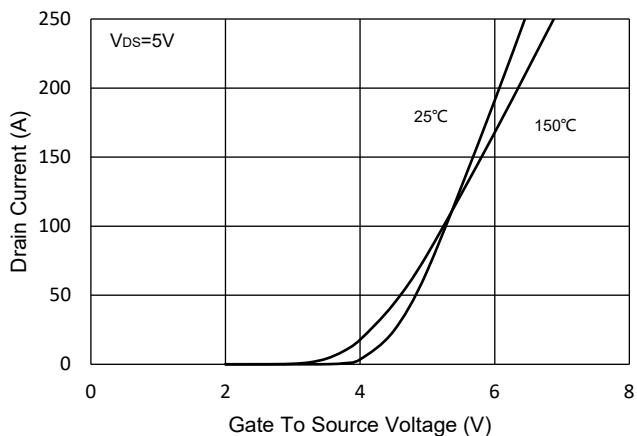


Fig.3 - $R_{DS(ON)}$ - V_{GS}

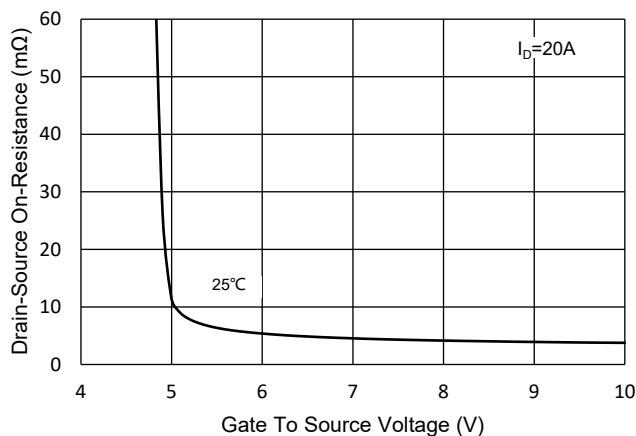


Fig. 4 - $R_{DS(ON)}$ - I_D

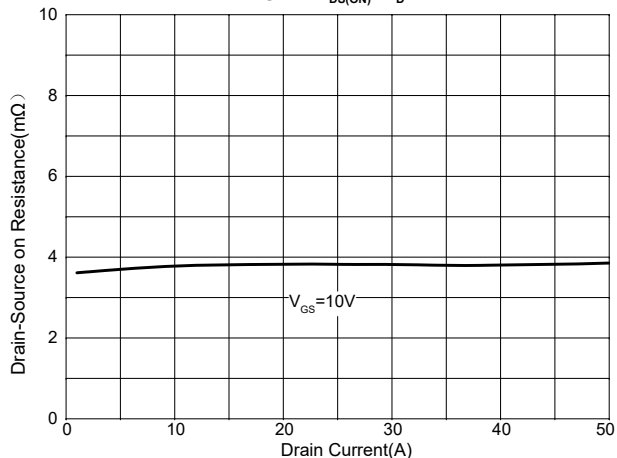


Fig.5 - Capacitance Characteristics

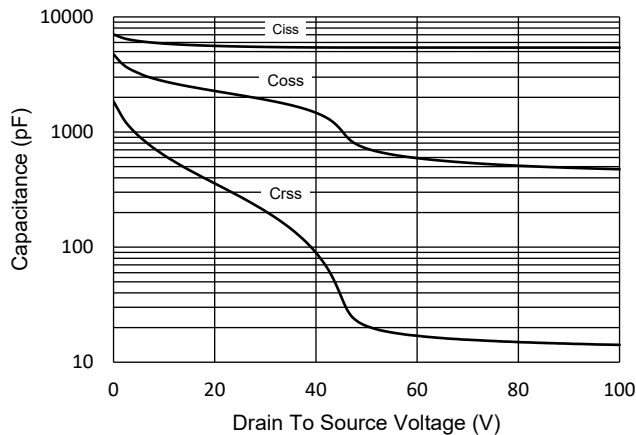
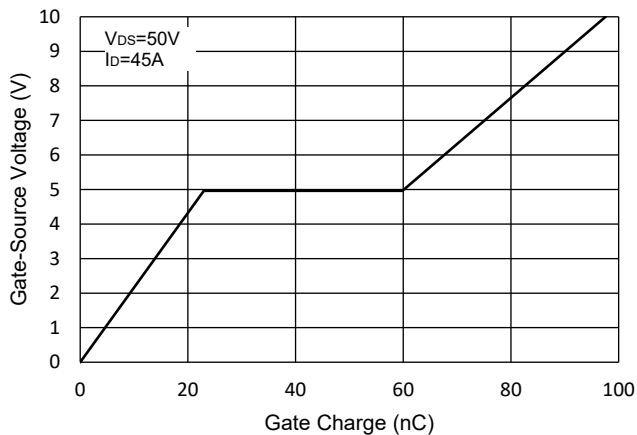


Fig.6 - Gate Charge



Curve Characteristics

Fig.7 - Normalized Threshold Voltage

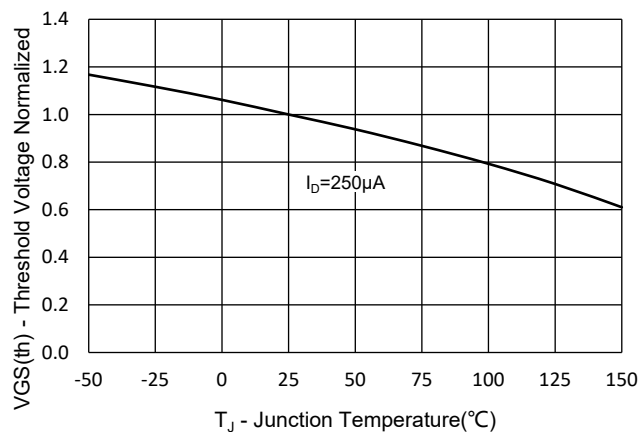


Fig.8 - Normalized On Resistance Characteristics

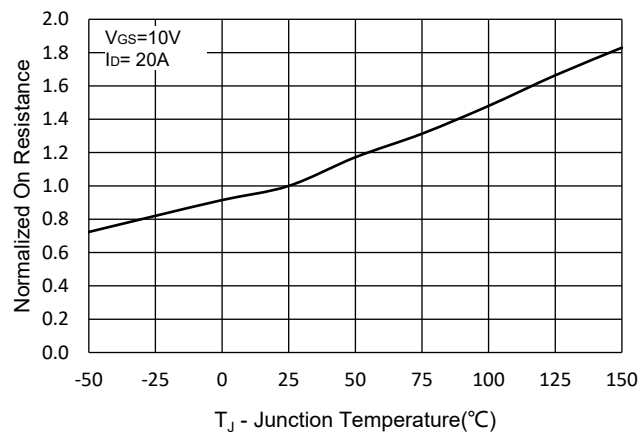


Fig.9 - I_S - V_{SD}

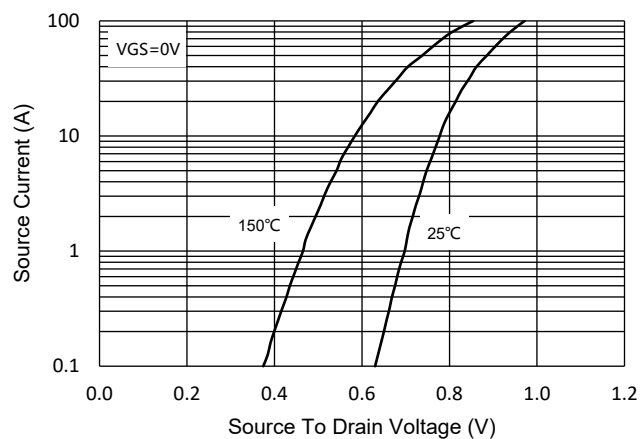


Fig.10 - Drain Current

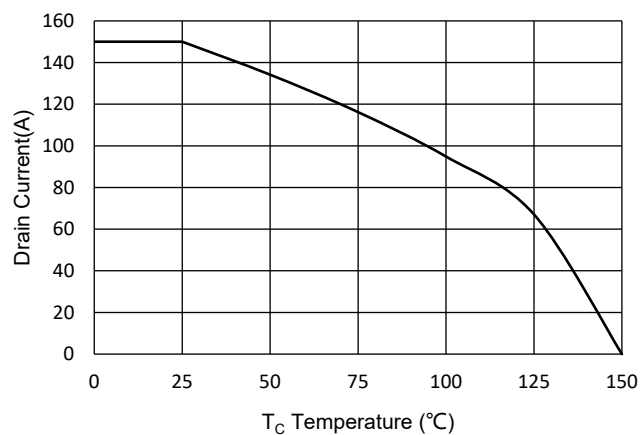
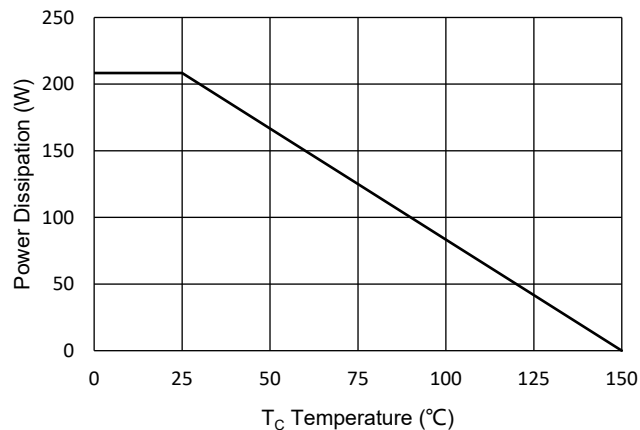


Fig.11 - PD Dissipation



Curve Characteristics

Fig.12 - Safe Operation Area

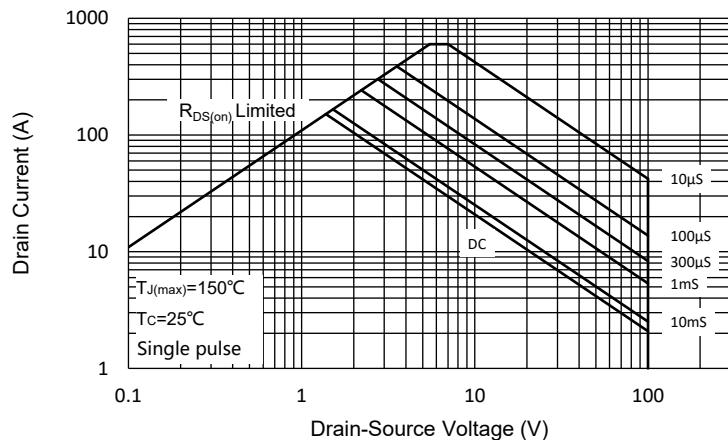
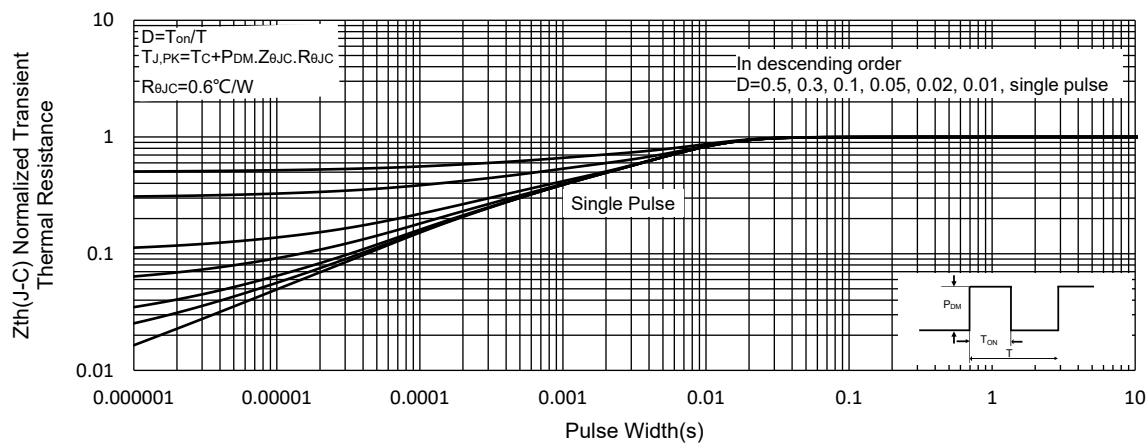


Fig.13 - Normalized Transient Thermal Impedance



Ordering Information

Device	Packing
Part Number-TP	Tape&Reel: 5Kpcs/Reel

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